☐ MN101C65C , MN101C65D

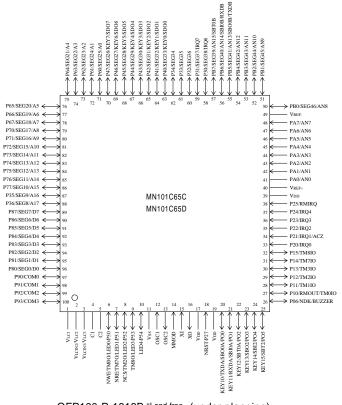
Туре	MN101C65C (under planning)	MN101C65D (under planning)				
ROM (x8-bit)	48 K	64 K				
RAM (×8-bit)	2 K	2 K				
Package	QFP100-P-1818B *Lead-free (under planning), LQFP100-P-1414 *Lead-free (under planning)					
Minimum Instruction Execution Time	0.1 μs (at 4.5 V to 5.5 V, 20 MHz) 0.25 μs (at 2.7 V to 5.5 V, 8 MHz) 62.5 μs (at 2.0 V to 5.5 V, 32 kHz)* * The lower limit for operation guarantee for flash memory built-in type is 2.5 V.					
Interrupts	 RESET • Watchdog • External 0 • External 1 • External 2 • External 3 External 4 (key interrupt selectable) • External 5 (key interrupt dedicated) • External 6 • External 7 Remote control • Timer 0 • Timer 1 • Timer 2 • Timer 3 • Timer 6 Time base • Timer 7 (2 systems) • Timer 8 (2 systems) • Serial 0 (2 systems) • Serial 2 • A/D conversion finish 					
Timer Counter	PWM output to large current terminal P50 possible) Clock source	ote control carrier, simple pulse width measurement) (square-wave/ requency; 1/1, 1/4, 1/16, 1/32, 1/64 of OSC oscillation clock frequency; frequency; external clock input e register 0				
	Timer counter 1 : 8-bit × 1 (square-wave output, event count, synchronous output event) Clock source					
	Timer counter 0, 1 can be cascade-connected.					
		o large current terminal P52 possible) requency; 1/1, 1/4, 1/16, 1/32, 1/64 of OSC oscillation clock frequency frequency; external clock input				
	Timer counter 3: 8-bit × 1 (square-wave output, event count, generation of remote control carrier, serial 0 baud rate timer) Clock source					
	Timer counter 2, 3 can be cascade-connected.					
	Timer counter 6 : 8-bit freerun timer Clock source					
	measurement, input capture) (square-wave/PWM output to large Clock source	m clock frequency; 1/1, 1/2, 1/4, 1/16 of OSC oscillation clock /16 of external clock input frequency				

Timer Counter (Continue)		Timer counter 8: 16 bit × 1 (square-wave/16-bit PWM output [duty continuous variable], event count, pulse width measurement, input capture) (square-wave/PWM output to large current terminal P53 possible) Clock source				
		Timer counters 7, 8 can be cascade-connected. (square-wave output, PWM, input capture, pulse width measurement is possible as a 32-bit timer.) Time base timer (one-minute count setting) Clock source				
Serial Interface		Serial 0 : synchronous type/UART (full-duplex) × 1 Clock source ····································				
		Seria	al 2 : synchronous type × 1 Clock source			
Remote Contr	ol Interface		ote control output: timer 0 and 3 output: the remote control carrier output of 1/2 and 1/3 duty. ote control reception: correspondence with low speed clock waiting correspondence with AEHA (Association for Electric Home Appliances) format (selection of a formart is available by the set-up)			
I/O Pins	I/O	77	Common use			
	Input	6	Common use Specified pull-up resistor available			
A/D Inputs		10-bit ×16-ch. (with S/H)				
LCD		47 segments × 4 commons (static, 1/2, 1/3, or 1/4 duty) LCD power supply separated from VDD (usable if VDD ≤ VLCD ≤ 5.5 V) LCD power step-up circuit contained (3/2, 2 and 3 times) LCD power shunt resistance contained				
Special Ports		Buzzer output, remote control carrier signal output, high-current drive port				

Parameter	Sumbal	Condition		Limit		
raiailletei	Symbol			typ	max	Unit
	IDD1	fosc = 20 MHz, VDD = 5 V		25	60	mA
Operating supply current	IDD2	fosc = 8 MHz, VDD = 5 V		10	25	mA
	IDD3	fx = 32 kHz, VDD = 3 V		30	100	μА
Cupply ourrent at UALT	IDD4	$fx = 32 \text{ kHz}, VDD = 3 \text{ V}, Ta = 25^{\circ}\text{C}$		4	8	μА
Supply current at HALT	IDD5	$fx = 32 \text{ kHz}, VDD = 3 \text{ V}, Ta = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			T.B.D(30)	μА
Supply ourrent at STOR	IDD6	VDD = 5 V, Ta = 25°C			2	μА
Supply current at STOP	IDD7	$VDD = 5 \text{ V}, \text{ Ta} = -40^{\circ}\text{C to} +85^{\circ}\text{C}$			T.B.D(50)	μА

Supply current

Pin Assignment



QFP100-P-1818B *Lead-free (under planning)
LQFP100-P-1414 *Lead-free (under planning)

Support Tool

In-circuit Emulator	PX-ICE101C / D + PX-PRB101C65-QFP100-P-1818B (under planning)	
Flash Memory Built-in Type	Туре	MN101CF65D (under planning)
	ROM (× 8-bit)	64 K
	RAM (× 8-bit)	2 K
	Minimum instruction execution time	0.1 µs (at 4.5 V to 5.5 V, 20 MHz)
		$0.25~\mu s$ (at $2.7~V$ to $5.5~V,~8~MHz)$
		62.5 µs (at 2.5 V to 5.5 V, 32 kHz)
	Package	QFP100-P-1818B *Lead-free (under planning),
		LQFP100-P-1414 *Lead-free (under planning)

MN101C65C , MN101C65D \square

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